





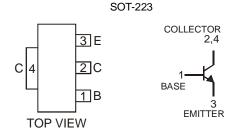
#### **Features**

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (DZT2907A)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

#### **Mechanical Data**

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)





Schematic and Pin Configuration

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Continuous Current	Ic	600	mA

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation @ T <sub>A</sub> = 25°C (Note 3)	$P_d$	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @T <sub>A</sub> = 25°C	$R_{ hetaJA}$	125	°C/W
Operating and Storage Temperature Range	$T_j$ , $T_{STG}$	-55 to +150	°C

Notes:

- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

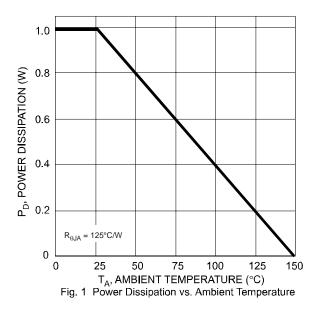
  Device mounted on FR-4 PCB pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

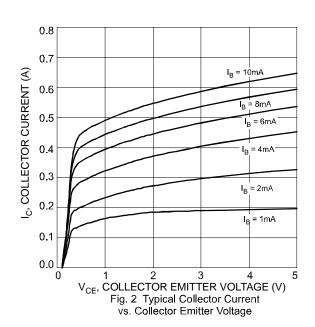


# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

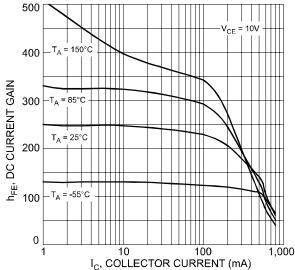
Characteristic	Symbol	Min	Max	Unit	Test Conditions		
OFF CHARACTERISTICS (Note 4)							
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	75	_	V	$I_C = 10\mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40	_	V	$I_C = 10 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6	_	V	$I_E = 10\mu A, I_C = 0$		
Collector Cut-Off Current	I <sub>CBO</sub>		10	nA	$V_{CB} = 50V, I_E = 0$		
Collector Cut-On Current			10	μΑ	$V_{CB} = 50V$ , $I_E = 0$ , $T_A = 150^{\circ}C$		
Emitter Cut-Off Current	I <sub>EBO</sub>	_	10	nA	$V_{EB} = 3V, I_{C} = 0$		
Collector-Emitter Cut-Off Current	I <sub>CEX</sub>		10	nA	$V_{CE} = 60V$ , $V_{EB(off)} = 3V$		
ON CHARACTERISTICS (Note 4)							
Collector-Emitter Saturation Voltage	\/	_	0.3	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
Concetor-Emitter Cataration Voltage	V <sub>CE(SAT)</sub>	_	1.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		
Base-Emitter Saturation Voltage	V25(045)	0.6	1.2	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
Dase Emilier Galdration Voltage	V <sub>BE(SAT)</sub>	_	2.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		
		35	_	>	$I_C = 0.1 \text{mA}, V_{CE} = 10 \text{V}$		
		50	_		$I_C = 1 \text{mA}, V_{CE} = 10 \text{V}$		
		75	_		$I_C = 10mA, V_{CE} = 10V$		
DC Current Gain	h <sub>FE</sub>	35	_		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}, T_A = -55 ^{\circ}\text{C}$		
		100	300		I <sub>C</sub> = 150mA, V <sub>CE</sub> = 10V		
		50	_		$I_C = 150 \text{mA}, V_{CE} = 1 \text{V}$		
		40	_		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$		
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency	f⊤	300		MHz	$I_C = 20 \text{mA}, V_{CE} = 20 \text{V}, f = 100 \text{MHz}$		
Output Capacitance	$C_{obo}$	_	8	pF	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		
Input Capacitance	$C_{ibo}$	_	25	pF	$V_{EB} = 0.5V$ , $I_{C} = 0$ , $f = 1MHz$		
SWITCHING CHARACTERISTICS							
Delay Time	t <sub>d</sub>	_	10	ns	$V_{CE} = 30V$ , $V_{EB(off)} = 0.5V$ , $I_C = 150mA$ , $I_{B1} = 15mA$		
Rise Time	t <sub>r</sub>	_	25	ns			
Storage Time	t <sub>s</sub>	_	225	ns	$V_{CE} = 30V$ , $I_C = 150mA$ , $I_{B1} = I_{B2} = 15mA$		
Fall Time	t <sub>f</sub>	_	60	ns			

Notes: 4. Measured under pulsed conditions. Pulse width = 300  $\mu$ S. Duty Cycle, d< = 2%.

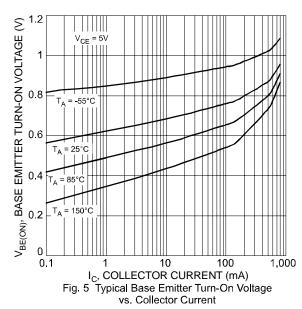








I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 3 Typical DC Current Gain vs. Collector Current



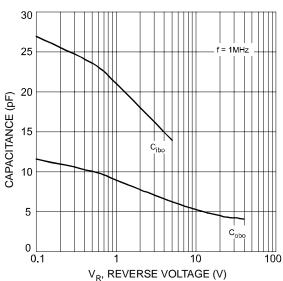


Fig. 7 Typical Capacitance Characteristics

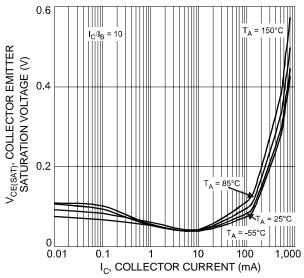


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

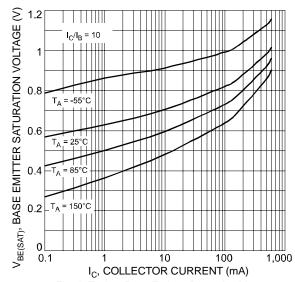
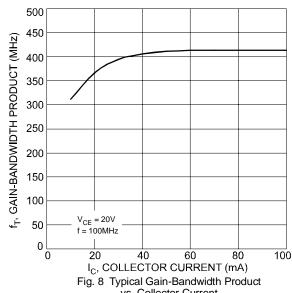


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current



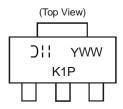


#### **Ordering Information** (Note 5)

Device	Packaging	Shipping
DZT2222A-13	SOT-223	2500/Tape & Reel

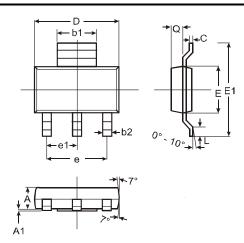
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



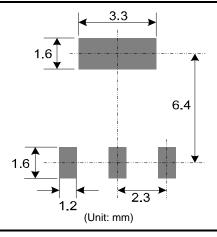
K1P = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year ex: 7 = 2007 WW = Week Code 01-52

# **Package Outline Dimensions**



SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
<b>A</b> 1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_		4.60		
e1	_	_	2.30		
L	0.55	0.75	0.65		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# Suggested Pad Layout: (Based on IPC-SM-782)



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